R ange of the  $t\{J \text{ m odel param eters for C uO}_2 \text{ plane: experim ental}$  data constraints.

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# A bstract

The t-J m odele ective hopping integral is determ ined from the three-band H ubbard m odel for the charge carriers in C uO<sub>2</sub> plane. For this purpose the values of the superexchange constant J and the charge-transfer gap E gap are calculated in the fram ework of the three-band m odel. Fitting values of J and E gap to the experimental data allows to narrow the uncertainty region of the three-band m odel parameters. As a result, the t=J ratio of the t-J m odel is xed in the range 2:4 2:7 for holes and 2:5 3:0 for electrons. Form ation of the Frenkel exciton is justified and the main features of the charge-transfer spectrum are correctly described in the fram ework of this approach.

 $75.10 \, Jm , 75.30 \, Ds$ 

#### I. IN TRODUCTION

A large amount of works dedicated to high- $T_c$  superconductors agree that an appropriate electronic model which contains all essential orbitals is the three-band Hubbard model [1{3]. Some other works developing a multiband approach [4{7] also support this belief.

It is also widely accepted that the low-energy physics of insulating compounds can be described by the Heisenberg Hamiltonian. According to the earlier work by Zhang and Rice [8] and latter studies [9]—[15] lightly doped systems are described by the simple t-J model. Dierent techniques provide dierent exactness of the three-band model to t-J model mapping and generate a wide type of generalizations [11,14,15].

In our previous works [12,13,15] a consistent low-energy reduction of the three-band model to the generalized t-J model in the realistic range of parameters has been performed. It has been shown [15] that the second-order corrections to the local energy of the carrier and its hopping integral are small (< 5%). The role of the next-nearest-neighbor terms has also been discussed.

It is commonly believed that the 90% or even higher accuracy of the t-J model as the low-energy electronic model for high- $T_c$  superconductors justiles its wider study [16{18}] and remains this model the main pretender in describing of the superconductivity in cuprates [19{21}]. Recent angle-resolved photoem ission experiments [22] can be interpreted as a direct support of some t-J model properties [23]. Some other anomalous behaviors of systems in normal state as well as superconductivity itself seem to be described in the framework of the t-J model [19{21}], [23].

The reasonable question from this point of view is: what is the role of either the three-band or more complex rst-principles models? There are several answers: (i) calculating parameters for the t-J model for real systems; (ii) giving insight into the experiments including not only the simple t-J model degrees of freedom.

In this paper we mainly address the question of the t-J m odel parameters. Superexchange constant J for the t-J model is directly measured [24,25]. Hence, the parameter to be

determ ined is the e ective nearest-neighbor hopping integral. The problem of its calculation is not connected with the accuracy of low-energy mapping from the three-band model, which is always very high, but results from uncertainty in the three-band model parameters. The three-band model in conventional formulation contains as inner parameters two on-site and one inter-site Coulomb repulsions, two hopping integrals, and split of the levels [1] which are not directly measurable. Some of them are fairly bad determined. This makes the calculation of the hopping integral for real systems questionable and even controversial.

We develop an obvious idea of xing the three-band model parameters by using experimental data. This idea has already been exploited in the cluster calculations for spectroscopic data [6] and for the superexchange J in our previous work [15]. Now, on the basis of better understanding of the low-energy model of the electronic system and magnetic polaron nature of the t-J model carriers [18,26,27], we calculate quite accurately the charge-transfer gap. Selfconsistent calculation provides a narrow range of possible values of t=J. Also, an excitonic feature of the charge-transfer spectrum is obtained in agreement with resent experiments [28].

Paper organized as follows. In Sec. II we discuss the low-energy limit of the three-band model and experimentally observable quantities. In Sec. III the calculation of the superexchange constant J and the charge-transfer gap  $E_{\rm gap}$  is produced. In Sec. IV we discuss the dependence J and  $E_{\rm gap}$  on the parameters of the three-band model and determine the range of the hopping parameter those electrons and holes. In Sec. V the properties of the excitonic state is considered. Sec. V I presents our results and discussions. The technical aspects of work are given in Appendix.

# II. THE LOW ENERGY LIM IT OF THE THREE BAND MODEL AND OBSERVABLE OUANTITIES

P reviously, it was suggested that the three-band H ubbard m odel is an appropriate starting point for describing the electronic structure of CuO<sub>2</sub> planes [1,2]. The Cu  $d_{x^2-y^2}$  orbital

and p (x;y) orbitals are strongly hybridizated. These orbitals are explicitly treated in the three-band model with the justiable assumption that other orbitals does not directly participate in the low-energy dynamics. The full Hamiltonian of the model is dened by [1]

$$H = H_{0} + H_{t} + H$$

$$H_{0} = \begin{pmatrix} X & X & X \\ d & n_{1}^{d} + p & n_{m}^{p} + U_{d} & n_{1}^{d} n_{1}^{d}; \\ X & M_{t} = t_{pd} & (d_{1}^{t} p_{m} + H x:) \\ & & (l_{m}^{t}) & (l_{m}^{t} + l_{m}^{t}) & (l_{m}^{t}) & (l_{m}^{t$$

in standard notation of holes at 0 (p) and Cu(d) sites. The sign convention for oxygen orbitals in  $H_t$  [15,29] is accepted. Our approach to description of low-energy properties of the above model [15] is based on taking into account the main Coulomb ( $U_d$ ) interaction exactly and the others as perturbations.

In order to justi cate this method we brie y describe here the magnitudes of the three-band model's parameters. Die erent experimental [6,7,30], atom ic [31], and band calculations [4,32,33] show that:  $U_d = 5$  7 eV [31], 7 11 eV [4,6],  $U_p = 3$  8 eV [7],  $V_{pd} = 0$  1:7 eV .  $U_p$  is always less than  $U_d$ . There is a general agreement for the Cu-O system that  $= p_{-d}$  is always > 0 and <  $U_d$  [30]. It rejects the facts that the rist hole in the unit cell is predom inantly at the Cu site and the added hole has an oxygen's character.  $t_{pd} = 1$  1:6 eV (and it is unlikely that it is less than 1 eV),  $t_{pp} = 0.5$  0.7 eV [4,32,33]. This set of magnitudes will be called hereafter the realistic region of parameters.

The consistent low-energy reduction of the three-band model to the generalized t-J model has been performed in previous works [12,13,15]. Our method of the low-energy reduction has been based on construction of a set of local states with dierent number of holes over the led atom ic orbitals. The most essential states are:

1. The vacuum state or the vacancy which is simply

$$\dot{\gamma} > = \dot{\gamma} > ; \tag{3}$$

2. The one-hole states which represent the ground state of CuO2 plane

where jd > and jq > are the copper and symmetrical oxygen hole states with spin projection, respectively.

3. The two-hole states which are the Zhang-Rice singlets:

$$jc > = U_1 jd " d #> + V_1 jq " q #>$$

$$+ W_1 (jd " q #> jd # q ">)= 2:$$
(5)

The coe cients U; V; U1; V1; W1 are functions of the parameters of the three-band model [15]. At half lling Ham iltonian (1,2) is reduced to the Heisenberg Ham iltonian with spin-1=2 which are antiferrom agnetically ordered due to the second-order virtual transitions through the set of two-hole states. Note, that the above named spins-1=2 are exactly states if V1 (Eq. (4)).

It has been shown [13,15] that for the case near to half lling the Ham iltonian of the three-band model is reduced to the Ham iltonian of the t-J like model of singlets, vacancies and spins:

$$H_{tJ} = (E_{v})^{X} X_{1}^{vv} + (E_{c} + )^{X} X_{1}^{cc}$$

$$X^{1} X_{1}^{v} + (E_{c} + )^{X} X_{1}^{cc}$$

$$X^{1} X_{1}^{v} X_{1}^{v} + (E_{c} + )^{X} X_{1}^{cc}$$

$$X^{1} X_{1}^{c} X_{1}^{c} X_{1}^{c}$$

$$X^{1} X_{1}^{c} X_{1}^{c} X_{1}^{c}$$

$$X^{1} X_{1}^{c} X_{1}^{c} X_{1}^{c}$$

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$$X^{1} X_{1}^{c} X_{1}^{c} X_{1}^{c} X_{1}^{c} X_{1}^{c}$$

$$X^{1} X_{1}^{c} X_{1$$

Where  $X_1^{ab}$  jal > < Ibj are the Hubbard operators at the site l,  $S_1 = X_1 = 2$ . The constants  $E_v$  and  $E_c$  are the local energies of the vacancy and singlet; is the chemical potential;  $t_e$  and  $t_h$  are the hopping integrals for the vacancy and singlet (electron and hole), respectively; J is the exchange constant. All ve parameters  $E_v$ ;  $E_c$ ;  $t_e$ ;  $t_h$  and J are functions of the three-band model parameters. It has been shown that relative magnitudes

of the omitted terms in the Hamiltonian  $H_{\rm t~J}$  (Eq. (6)) are of the order of ten percent [13,15].

We believe that the Ham iltonian (6) describes many in portant properties of the cuprates. Therefore, the real values of its parameters are of great interest. As was noted above, the parameters of the primary model (1,2) are known with low precision. In this situation calculation of the observable quantities is an urgent issue since it provides a way to x parameters of Ham iltonians (1,2) and (6). The best-defined experimental values which we can describe quite accurately are the superexchange constant J and the charge-transfer gap  $E_{\rm gap}$ . The experimental values of J are 0:14 eV and 0:17 eV for the lantan and yttrium systems, respectively [24,25]. These values of J follow from measurement of the velocity of sound for magnons. The value of the charge-transfer gap is known from a variety of optical measurements [28,30,33,34] and is near to 2:0 eV .0 bservation of photoconductivity at the same energies shows that the excitations result in separated electrons and holes [28,34]. We have taken most of clear experimental features of the charge-transfer spectrum from Ref. [28] where photoconductivity as well as refertivity data for  $La_2CuO_4$  are presented.

# III. CALCULATION OF THE OBSERVABLE QUANTITIES

The expression for the AF coupling constant J in the fram ework of our approach is

$$J = 2h_1 V^4 U_p + \sum_{n=1}^{X} x_n \frac{D_n \hat{J}}{E_n} :$$
 (7)

The rst term in Eq. (7) represents the exchange energy between two holes (spins) due to the repulsion at an oxygen. This contribution has the ferrom agnetic sign and arises as an exchange interaction between the hole states (4) due to their nonlocal nature. The constant V is defined in Eq. (4),  $h_1$  is in Appendix. The second term in Eq. (7) represents the correction to the energy due to the virtual transition of hole from the state Eq. (4) into the two-hole states and back [15]. Here n numerates the two-hole states; matrix elements of transitions  $D_n$  were calculated in Ref. [15],  $E_n$  are differences in energies between the

energy of the vacancy and two-hole states at neighbor sites and the ground state energy (see Fig. 1); the coe cients  $x_n = 4$  for the singlet and  $x_n = 2$  for triplet two-hole states.

The most general expression for the charge-transfer energy is:

$$E_{gap} = E_{m in}^{N-1} E_{g}^{N} + E_{m in}^{N+1} E_{g}^{N};$$
 (8)

where N refers to the total number of electrons,  $E_g^N$  is the ground state energy,  $E_{m \text{ in}}^{N-1}$  is the minimal energy of a system with one removed and added electron. For our system Eq. (8) can be specified as

$$E_{gap} = E_{gap}^{0} + E_{e} + E_{h};$$
 (9)

where  $E_{gap}^{0}$  is the difference in energies between a singlet and vacancy at local states separated by large distance and the ground state (see Fig. 2);  $E_{e}$  and  $E_{h}$  are depths of bands for electron and hole (vacancy and singlet).  $E_{gap}^{0}$  can be calculated in the fram ework of the three-band model, whereas for the calculation of  $E_{e}$  and  $E_{h}$  we will use the t-J model.

The expression for  $E_{qap}^{0}$  in terms of Eq. (6) is very simple:

$$E_{\text{gap}}^{0} = E_{c} + E_{v}; \qquad (10)$$

The values of E e and E h can be determined from numerous analytical and numerical calculations [16]—[19], [23,26,27,35,36] of the dispersion relation (k) for one hole in the t-U model on an antiferrom agnetic background. There is a general agreement that the hole (or vacancy) on the antiferrom agnetic background creates a magnetic polaron of a small radius [17,26], or, in the other words, the carriers are strongly dressed by the spin waves [23]. The in uence of antiferrom agnetizm and strong correlations are manifested in a special form of dispersion relation (k). For our calculations we use the results from the earlier work by Sushkov Ref. [18] where hole wave function and (k) were obtained variationally:

(k) = 1:32J  
+ 
$$\frac{1}{2}$$
 ~J  $\frac{q}{2J^2 + 16t^2[(1+y) (x+y)]_k^2}$ 

and

$$E = 132J + \frac{1}{2}$$
  $^{\circ}J$   $^{\circ}Z^{2} + 16t^{2}(1 + y)$  ; (11)

where for Neel background  $^{\sim}=1:33; x=0:56; y=0:14$ . Loss of energy due to the broken AF bonds (four per carrier) is included. Result for the bottom of the band at t=J = 2.5 from Eq. (11) E = 1.2t coincides almost exactly with the recent results of the G reen function M onte Carlo calculation by D agotto, N azarenko, and B on in segni [23] E = 1.255t. Formula (11) is quite good up to t=J 5 [18].

Let us discuss the characteristic values of all essential param eters which determ ine the observable quantities J and  $E_{\rm gap}$  (8), (9). In the realistic region of param eters of the three-band model one can easily obtain the experimental values J=0.14 eV and J=0.17 eV for lantan and yttrium systems. The value for  $E_{\rm gap}^0$  (10) was obtained in Ref. [15] and is equal to 3.2 eV in the same region of parameters. The characteristic values of  $E_{\rm e}$  and  $E_{\rm h}$  (11) depend on ratios t=J for electrons and holes. These ratios weakly dier and for a typical value of t=J=2.5 we have  $E_{\rm e}$   $E_{\rm h}$  0.42 eV. Thus, the overall gain in energy due to magnetic polaron formation is of the order of 1 eV, which is comparable with the experimentally observed  $E_{\rm gap}$  2.0 0.1 eV. Therefore, the magnetopolaron e ect gives essential contribution in the value of the charge-transfer gap.

In the paper [28] it was proposed that the usual phonon polaron elect contributes in the observable values of the charge-transfer spectrum. The corresponding gain in energy was estimated as 0:5 eV. However, we suppose that due to the Frank-Condon principle the usual polaronic elect does not contribute in the optical transition. Magnetopolaron elect has no such restriction since it involves electronic degrees of freedom only. We will return to this question in Discussions.

#### IV.PARAM ETERS SENSITIVITY

Thus, we ind superexchange constant J (7) and charge-transfer gap E  $_{\rm gap}$  (9) ( [7,24,37]) as functions of the three-band model parameters:

$$J = J (t_{pd}; t_{pp}; ; U_{d}; U_{p}; V_{pd});$$

$$E_{qap} = E_{qap} (t_{pd}; t_{pp}; ; U_{d}; U_{p}; V_{pd}):$$
(12)

Both observable quantities are strongly depend on hopping integrals and  $= p_{d}$ , that provides the way of xing these latter by the experimental values of the rst.

A swasdiscussed earlier, abundance of the parameters makes questionable the calculation of the elective hopping integral for the t-J model from the three-band model for real CuO  $_2$  planes. While Coulomb repulsions are known with a fair precision (30% 50%), the situation is complicated due to a very low precision of the direct determination of  $t_{pd}$ ;  $t_{pp}$  and , which mostly a ect all elective parameters. Previously, the above parameters have been determined from the analysis of spectroscopic data [6,7]. In our recent work we tied to experimental value of J [15].

Now, on the basis of a better understanding of the charge-transfer process and more accurate calculations, xing of the worse known parameters using experimental values of J and  $E_{gap}$  suggests itself. We will show that this procedure keeps elective  $t_h$  inside a narrow enough region.

Firstly, for further discussion we de ne 0-0 hopping as  $t_{pp} = t_{pd}$ . In order to characterize the above mentioned strong dependence of the parameters (12) one can calculate  $(t_{pd})$  at xed J or at xed E  $_{gap}$ , with other parameters (C oulomb repulsions and ) as constants in the realistic region. We evaluate  $vst_{pd}$  at J=140 meV and 170 meV, E  $_{gap}=2.0$  eV and 2.5 eV (see Fig. 3). Note that the proles of the curves resemble those at the diagram of U (t) for the simple one-band Hubbard model where E  $_{gap}=U+2W$ , W=t,  $J=4t^2=U$ , and the crossing point uniquely determines U and t.

To be more special, we arrive determined for constant J at an arbitrary t  $_{pd}$  and further moved up or down along the curve J = const to x the value of  $E_{gap}$ . We used the data for  $La_2CuO_4J = 140$  m eV [25] and  $E_{gap} = 2:1$  eV (photoconductivity) [28]. Figures 4,5,6 show the parameter of our prime interest: the elective integral for hole in the t-J model. Parameter  $= t_{pp} = t_{pd}$  is 0.5;0:7;0:3 for Figs. 4,5,6, respectively. In all gures simple dotted

curve corresponds to  $V_{pd} = U_p = 0$ , dotted ones with crosses  $V_{pd} = 0$ ,  $U_p = 3$  eV, 6 eV, dotted ones with triangles  $V_{pd} = 0.5$  eV 1 eV,  $U_p = 0$ , and full curves correspond to including both Coulombs  $V_{pd} = 0.5$  eV,  $U_p = 3$  eV (upper),  $V_{pd} = 1$  eV,  $U_p = 6$  eV (lower). The maximum on the rst three curves is due to transition from  $> U_d$  (unrealistic range) to  $< U_d$ . All variations of  $t_h$  ( $U_d$ ;  $V_{pd}$ ;  $U_p$ ; ) actually show only weak dependence, and in the most preferential region, when all Coulombs are included,  $t_h$  lies between (2.4 2:7)J. We believe, that our consideration is quite accurate and well justified. Hence, one can hope that the interval for t=J obtained above provides the basis for quantitatively correct calculations in the fram ework of the t-J model. For example, for the recently proposed mechanism of superconductivity in the t-J model which provides a very t-J-sensitive (exponentially) gap value [20].

A lso some other features can be achieved. Figures 7,8,9 represent elective hopping  $t_{\rm e}$  j for vacancy,  $t_{\rm pd}$  and respectively, vs other parameters. Here always = 0.5. Strong support of our xing procedure is that selfconsistently determined  $t_{\rm pd}$  and (Figs. 8,9) lie in the most appropriate region. From our calculation  $t_{\rm pd} = 1.2$  1.4 eV, = 2.5 4.5 eV, that is really close to cluster calculation of E skes and Sawatzky [7] and to the results of other groups [4,32,33].

### V.EXCITONIC STATE

The problem of consistently taking into account the Coulomb interaction of the carriers in the fram ework of the t-J - like model remains open. Several recent works are devoted to this problem [38].

As was suggested earlier [1], the short-range part of this Coulomb interaction may be kept by inclusion of the nearest-neighbour Cu-O repulsion. Since  $V_{pd}$  is included in our elective model, one can expect that some elects will be caught.

In the recent work [28] a kink in the optical re ectivity somewhere below the chargetransfer peak (at 1:75 eV) was observed. Since it had no associated photoconductivity, it was related to creation of exciton. An essential role of the short-range Coulomb interaction was also discussed in Ref. [28]. In our way of reasoning the exciton state, if it exists, is the Frenkel exciton, because of short-range nature of interactions.

Now it is evident that an elective attraction can result from pure magnetopolaron elect in the t-J model [18,36]. As was shown in works [35,36], "contact" interaction of two holes (without charge) dressed by spin luctuations is attractive for a special symmetry of the wave-function. However, the associated energy is very small (J=3 0:04 eV).

It is possible to combine the ideas of the short-range Coulomb and magnetopolaron e ects. The di erence between E  $_{\rm gap}^0$  (10) when hole and electron are separated and E  $_{\rm n}$  (Fig. 4) (where n denotes the lowest singlet) when they are close, is the e ective Coulomb attraction of the "bare" hole and electron (singlet and vacancy). We write an addition to Eq. (6) as

$$H_{c} = V_{c} \qquad n_{1}^{e} n_{1}^{h} ;$$
 (13)

where  $n^e$  is the electron number operator,  $n^h$  is the hole number operator. We have found that  $V_c$  is really almost independent from  $U_d$  and  $U_p$  and  $V_c$  0:4 $V_{pd}$ . "Bare" electron-hole attraction itself does not mean Frenkel's exciton e ect. One has to show that "dressed" electron and hole placed closely possess the lower energy than the mobile ones. In order to specify the magnetopolaronic language we reproduce here the wave function of the magnetic polaron from the Ref. [18]. For the Ising background it has the more simple form:

$$d_{n}^{+} = \frac{1}{N = 2} \sum_{n=1}^{X} d_{n}^{+} \exp(ik r_{n});$$

$$d_{n}^{+} = h_{n}^{+} + S_{n}^{+} \sum_{n=2}^{X} h_{n}^{+};$$
(14)

where n 2 sublattice with the spin s = 1=2,  $h_n^+$  primarily hole operators; at t=J > 1,  $^2$  1=2,  $^2$  1=8. Thus, ansatz consist of mixture of "bare" hole and holes with one overturned spin. Contact interaction of these polarons with opposite spins was considered in Ref. [36] (see Fig. 10). The gain in energy for "attracting polarons" arises from the pure t-J model e ects [36] and e ective Coulomb attraction (13). The loss in energy is

from restriction of the mobility. Competition of these evident e ects (without Coulomb interaction) provides bound states up to t=J=2 3 [35,36]. Simply acting in a spirit of magnetic polaron interaction [36] we obtain E  $_{\rm exc}=0.35{\rm V_c}$ . Thus, at  ${\rm V_{pd}}=1$  eV, E  $_{\rm exc}=0.14$  eV.

M ore accurate variational construction of the exciton-m agnetopolaron wave-function (on the Ising background) yields E  $_{\rm exc}$  0.5V $_{\rm c}$  (at t=J = 2.5 3). This wave-function consists of the m ixture of "bare" hole and electron at neighbor sites and hole and electron with overturned spins. It is schematically shown in Fig. 11a. Thus, at V $_{\rm pd}$  = 1 eV, E  $_{\rm exc}$  ′ 0.2 eV, that is slightly less than the observed E  $_{\rm exc}^{\rm exp}$  = 0.25 0.35 eV [28]. In our calculations the interaction between next-nearest-neighbor magnetic polaron was neglected, which produced smalle ect for the pure t-J model [36] but may be essential for the problem with attraction. (These con gurations are shown in Figs. 11b,c). Also, the answer may partly lie in the rest of the long-range C oulomb interaction.

#### VI.DISCUSSIONS

The detailed quantitative consideration of some of the electric parameters of the low-energy models related to description of the high  $-T_c$  superconductors presented in this work relies heavily on our earlier works. In these works consistent mapping of the three-band Hubbard model onto the electric to model ([12,13,15]) has been produced. Taking into account all essential interactions enables us to correctly calculate local energies of various set of states with different number of particles and matrix elements of interesting transitions. Combination of properties of the local "bare" hole and electron (ZR-singlet and vacancy) and their magnetic polaron nature as the carriers allows us to approach the calculation of some observable quantities adequately.

We have calculated the superexchange J and charge-transfer gap  $E_{\rm gap}$ . Their experimental values strongly constrict a possible variation interval for the quantity of great interest: the t=J ratio in the t-J m odel. Selfconsistent calculation of this ratio for a wide range of pa-

ram eters places it into the region t=J=2.4-2.7. Narrowed ranges for the three-band model parameters have also been determined:  $t_{pd}=1.2-1.4$  eV, =2.5-4.5 eV. They coincide quite well with earlier cluster calculations, that supports our selfconsistent procedure. An excitonic state of the Frenkel type induced by the short-range C oulomb interaction with the energy lower than the charge-transfer transition approximately by 0.2 eV is found.

We have also compared the width of the peak in the  $_2$ (!) at 2:3 eV from Ref. [28] which is of the order of 0:5 eV with the total width of the charge-transfer spectrum. This total width is equal to the combined width of the vacancy and singlet bands. A coording to Eq. (11), the width of the hole band is W  $_h$  = 2:0J at  $t_h$  = 2:55J and width of the electron band is W  $_e$  = 2:75J. Resulting total width of the charge-transfer spectrum is about 0:6 eV. Thus, the narrowness of the  $_2$ (!) spectrum can also be easily reproduced by magnetic polaron language.

One of the essential questions for the  $CuO_2$  -planes systems, which we only brie y touched, is the phonon polaron e ect. If it does not have a projection on optics, or, as we believe, the Frank-Condon principle is applicable, our calculated  $t_h$ =J ratio is the upper limit of the real parameter. This is due to mass renormalization for real carriers. There is another view on the polaron e ect (see Ref. [28,39]). It is stated that electron-phonon interaction lies in an intermediate range and thus the Frank-Condon principle is not obeyed. If such is the situation, we underestimate the depth of the bands (or overestimate  $E_{gap}$ ), and e ective  $t_h$  should be increased. Our estimation shows that this increasing of  $t_h$  is no more than 30%. Naturally, this problem requires additional investigations.

# A cknow ledgm ents

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# APPENDIX:

In this Appendix we present some details of the technical treatment of the problems discussed in the paper. A coording to our previous work [15], we use the following transformation from the primary oxygen  $p_{lx}$ ;  $p_{ly}$  operators to the operators  $q_l$ ;  $q_l$  of the symmetrical and antisymmetrical oxygen states:

$$(q_1; q_1) = \sum_{k=1}^{X} [p_{ka} \cos(k_x=2) p_{kb} \cos(k_y=2)]$$

$$(1 + k)^{1=2} \exp(ikl); \qquad (A1)$$

where  $p_{ka}$  is the Fourier im age of  $p_{lx}$  for  $q_l$  and  $p_{ly}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$  and  $p_{lx}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$ ;  $p_{kb}$  is the Fourier im age of  $p_{ly}$  for  $q_l$ ;  $p_{lx}$  and  $p_{lx}$  is produced over the Brillouin zone, and the lattice constant  $p_{lx}$  and  $p_{ly}$  for  $p_{ly}$  is the Fourier im age of  $p_{ly}$  for  $p_{ly}$  for  $p_{ly}$  is the Fourier im age of  $p_{ly}$  for  $p_{ly}$  for  $p_{lx}$  is the Fourier im age of  $p_{ly}$  for  $p_{lx}$  is the Fourier im age of  $p_{ly}$  for  $p_{lx}$  is the Fourier im age of  $p_{ly}$  for  $p_{lx}$  is the Fourier im age of  $p_{ly}$  for  $p_{lx}$  is the Fourier im age of  $p_{ly}$  for  $p_{lx}$  is the Fourier im age of  $p_{ly}$  for  $p_{lx}$  is the Fourier im age of  $p_{lx}$  for  $p_{lx}$  is the Fourier im age of  $p_{lx}$  for  $p_{lx}$  in  $p_{lx}$  in  $p_{lx}$  in  $p_{lx}$  is the Fourier im age of  $p_{lx}$  for  $p_{lx}$  in  $p_{lx}$ 

Since the groundstates of both undoped and doped systems do not consist of antisymm etrical oxygen state [6,7,15], the reform ulated H am iltonian (1,2) where only essential degrees of freedom are kept, is conveniently expressed through the local and hopping parts [15]. The local part is:

with 
$$S_1^q = \frac{1}{2}q_1^+$$
  $q_1$ ;  $n^q = n_{1"}^q + n_{1\#}^q$ : (A 3)

The hopping part is:

All constants; f;h in Eqs. (A2,A4) are of Wannier nature. Their Fourier images and magnitudes are given in Ref. [15]. In order to group them together we reproduce

$$_0$$
= 0.9581  $_1$ = 0.1401  $_0$ = 1.4567  $_1$ = 0.2678  $f_0$ = 0.9180  $f_1$ = 0.2430  $h_0$ = 0.211  $h_1$ = 0.059  $f_0$ = 0.1342  $h_0$ = 0.030 .

We have treated the H am iltonian H  $_{loc}$ + H  $_{int}$  (A 2) in the selfconsistent m ean-eld approximation [15] that enables us to solve the problem of the local states at site with dierent number of holes. The matrix elements of the H am iltonian (A 4) between states with a singlet or vacancy at dierent sites in initial and nal states lead to the following expression for the hopping constants:

$$t_{h} = 2t_{1} (W_{1}V^{0} \stackrel{p}{=} \overline{2}U_{1}U^{0}) (W_{1}U^{0} \stackrel{p}{=} \overline{2}V_{1}V^{0})$$

$$+ t_{p_{1}} (W_{1}U^{0} \stackrel{p}{=} \overline{2}V_{1}V^{0})^{2} = 2$$

$$(V_{pd}f_{1}W_{1}U^{0} \stackrel{p}{=} \overline{2}U_{p}h_{1}V_{1}V^{0}) (W_{1}U^{0} \stackrel{p}{=} \overline{2}V_{1}V^{0});$$

$$t_{e} = 4t_{1}U^{0}V^{0} t_{p_{1}} (V^{0})^{2}; \qquad (A 5)$$

where U  $^{0}$ ; V  $^{0}$  are the coe cients of jf > -state nearest to singlet, U  $^{00}$ ; V  $^{00}$  -those nearest to vacancy. The coe cients U  $^{0}$ ; V  $^{0}$  and U  $^{00}$ ; V  $^{00}$  are slightly di erent from the ones in Eq. (4) due to a distortion of jf > -states by the nearest vacancy or singlet. This distortion has its origin in the short-range C oulomb repulsions due to U<sub>p</sub> and V<sub>pd</sub> terms in the H am iltonian (2). Note that it changes the energy of the jf > -states nearest to a vacancy or singlet. We

take this e ect into consideration when we calculate the quantity E  $_{\rm gap}^{0}$ . Thus, we have for the total energies E  $_{\rm c}$  and E  $_{\rm v}$  for a singlet and a vacancy Eq. (10)

$$E_c = E_s + 4E_{fs}$$
  $5E_f$ ;  
 $E_v = E_0 + 4E_{f0}$   $5E_f$ ; (A 6)

where  $E_s$  and  $E_0$  are the local energies of singlet and vacancy;  $E_{fs}$  and  $E_{f0}$  are the energies of the jf > -states nearest to a singlet or vacancy;  $E_f$  is the energy of jf > -state in an undoped sample. These states are schematically shown in Fig. 2.

When the vacancy and the two-hole state are created at the neighbour sites (see Fig. 1) the dierence in energy between this state and the ground state is determined by the relation

$$E_n = E_n + E_0 + 3E_{fs} + 3E_{f0} + 8E_f$$
: (A 7)

These energies  $E_n$  are involved in calculation of the superexchange constant J (Eq. (7)) and in the energy of the Coulomb attraction of a singlet and vacancy in Sec. V.

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#### FIGURES

FIG. 1. The nearest-neighbor two-hole state and vacancy. Black circle denotes two-hole state, empty circle denotes vacancy. Crosses are one hole states (spins).

FIG. 2. The separated ZR singlet (hole) and vacancy (electron). Black circle denotes singlet, empty circle denotes vacancy. Crosses are one-hole states (spins).

FIG. 3. vs  $t_{pd}$  at constant J or  $E_{gap}$ .  $U_d = 7$  eV,  $U_p = 3$  eV,  $V_{pd} = 1$  eV,  $t_{pp} = t_{pd} = 0.5$ . Full curve -J = 140 m eV, dashed curve -J = 170 m eV, full curve w ith m arkers  $-E_{gap} = 2.0$  eV, dotted curve  $-E_{gap} = 2.05$  eV.

FIG. 4. E ective hopping integral for t-J m odelhole  $vsU_d$ . D otted line  $-V_{pd} = U_p = 0$ , dotted with crosses  $-V_{pd} = 0$ ,  $U_p = 3$ , 6 eV, dotted with triangles  $-U_p = 0$ ;  $V_{pd} = 0$ 5, 1 eV, full curves  $-V_{pd} = 0$ 5 eV,  $U_p = 3$  eV (upper),  $V_{pd} = 1$  eV,  $U_p = 6$  eV (lower), = 05.

FIG. 5. All notations as for Fig.4; = 0.7.

FIG. 6. All notations as for Fig.4; = 0.3.

FIG. 7. E ective hopping integral for electron in the t-J model vs  $U_d$ , curves markers as for Fig.4; = 0.5.

FIG. 8. Cu-O hopping integral vs  $U_d$ , curves m arkers as for Fig.4; = 0.5.

FIG.9.  $vsU_d$ ; = 0.5.

FIG. 10. Con guration of interacting magnetic polarons from Ref. [36].

FIG. 11. (a) Exciton-magnetopolaron; (b),(c) next-nearest-neighbor magnetic polarons.